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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR Phase-out/Discontinued PA2710GR

SWITCHING P-CHANNEL POWER MOS FET

DESCRIPTION

The µPA2710GR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Li-ion battery protection circuit.

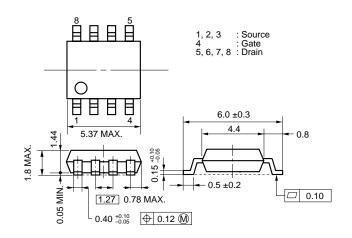
FEATURES

- · Low on-state resistance
 - $R_{DS(on)1} = 5.5 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = -10 \text{ V, Ip} = -7.5 \text{ A)}$
 - $R_{DS(on)2} = 9.0 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = -4.5 \text{ V, Ip} = -7.5 \text{ A)}$
- $R_{DS(on)3} = 11 \text{ m}\Omega \text{ MAX.}$ (Vgs = -4.0 V, ID = -7.5 A)
- Low Ciss: Ciss = 4300 pF TYP.
 - Small and surface mount package (Power SOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA2710GR	Power SOP8

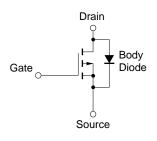
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (Ves = 0 V)	VDSS	-30	V
Gate to Source Voltage (Vps = 0 V)	Vgss	∓20	V
Drain Current (DC)	I _{D(DC)}	∓15	Α
Drain Current (pulse) Note1	I _{D(pulse)}	∓100	Α
Total Power Dissipation Note2	P _{T1}	2	W
Total Power Dissipation Note3	P _{T2}	2	W
Channel Temperature	Tch	150	°C
Storage Temperature	T_{stg}	-55 to + 150	°C
Single Avalanche Current Note4	las	–15	Α
Single Avalanche Energy Note4	Eas	22.5	mJ

EQUIVALENT CIRCUIT



- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1%
 - 2. Mounted on ceramic substrate of 1200 mm² x 2.2 mm
 - 3. Mounted on a glass epoxy board (1 inch x 1 inch x 0.8 mm), PW = 10 sec
 - **4.** Starting T_{ch} = 25°C, V_{DD} = -15 V, R_G = 25 Ω , L = 100 μ H, V_{GS} = -20 \rightarrow 0 V

Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately Remark degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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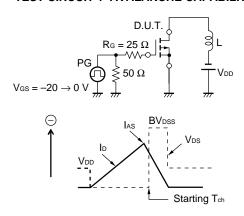


★ ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

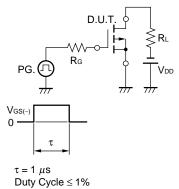
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	V _{DS} = -30 V, V _{GS} = 0 V			-1	μΑ
Gate Leakage Current	Igss	V _G S = ∓20 V, V _D S = 0 V			∓100	nA
Gate Cut-off Voltage Note	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.0		-2.5	V
Forward Transfer Admittance Note	yfs	$V_{DS} = -10 \text{ V}, I_{D} = -7.5 \text{ A}$	14	31		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = -10 V, I _D = -7.5 A		4.7	5.5	mΩ
	R _{DS(on)2}	VGS = -4.5 V, ID = -7.5 A		6.4	9.0	mΩ
	R _{DS(on)3}	V _{GS} = -4.0 V, I _D = -7.5 A		7.2	11	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		4300		pF
Output Capacitance	Coss	V _G S = 0 V		1200		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		690		pF
Turn-on Delay Time	td(on)	$V_{DD} = -15 \text{ V}, I_D = -7.5 \text{ A}$		11		ns
Rise Time	tr	V _{GS} = -10 V		22		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		420		ns
Fall Time	t _f			240		ns
Total Gate Charge	Q _G	V _{DD} = -24 V		97		nC
Gate to Source Charge	Qgs	V _G S = -10 V		12		nC
Gate to Drain Charge	Q _{GD}	I _D = -15 A		29		nC
Body Diode Forward Voltage	V _F (S-D)	IF = 15 A, VGS = 0 V		0.79		V
Reverse Recovery Time	trr	IF = 15 A, VGS = 0 V		119		ns
Reverse Recovery Charge	Qır	di/dt = 50 A/μs		84		nC

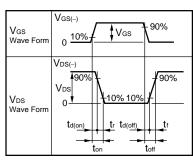
Note Pulsed PW≤350 μs, Duty Cycle≤2%

TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME





TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} \text{D.U.T.} & \\ \text{Ig} = -2 \text{ mA} \\ \hline \\ \text{PG.} & \\ \hline \\ \end{array} \begin{array}{c} \text{So } \Omega \\ \hline \\ \end{array} \begin{array}{c} \text{VDD} \\ \hline \\ \end{array}$$

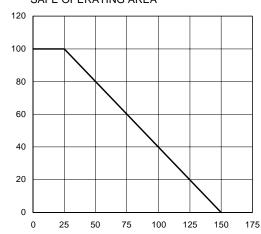
dT - Percentage of Rated Power -

lo - Drain Current - A



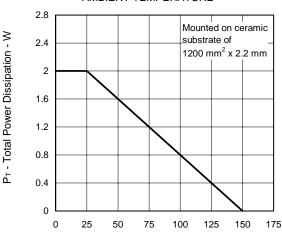
TYPICAL CHARACTERISTICS (TA = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



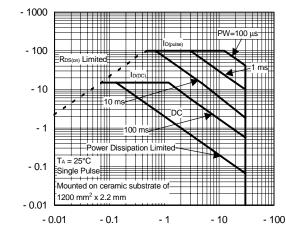
TA - Ambient Temperature - °C

TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



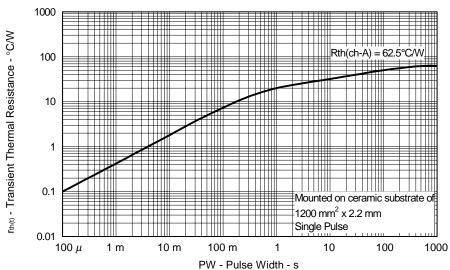
T_A - Ambient Temperature - °C

★ FORWARD BIAS SAFE OPERATING AREA



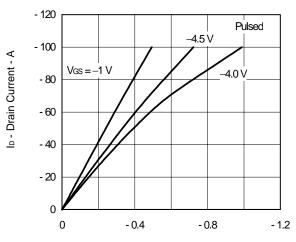
V_{DS} - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



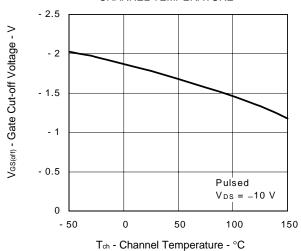
| y_{fs} | - Forward Transfer Admittance - S

★ DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

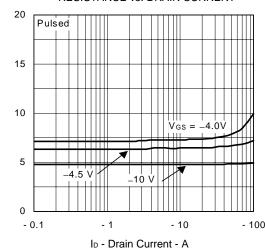


V_{DS} - Drain to Source Voltage - V

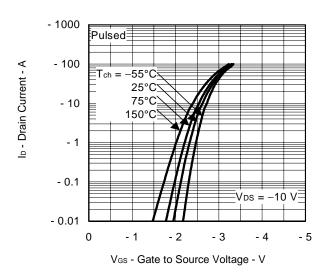
★ GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



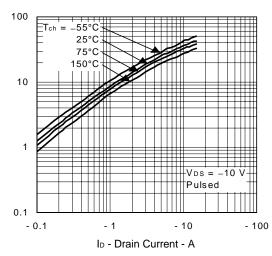
★ DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



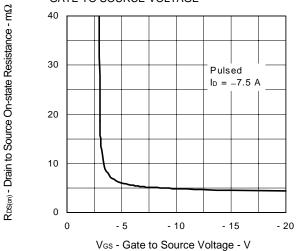
★ FORWARD TRANSFER CHARACTERISTICS



★ FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



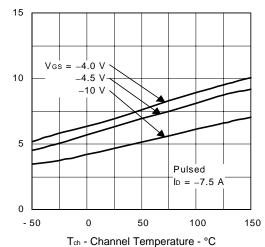
★ DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



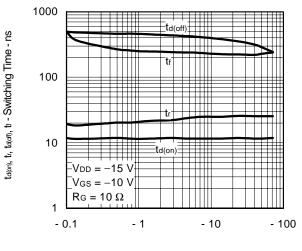
R_{DS(m)} - Drain to Source On-state Resistance - mΩ

RDS(m) - Drain to Source On-state Resistance - m\Omega

DRAIN TO SOURCE ON-STATERESISTANCE vs. CHANNEL TEMPERATURE

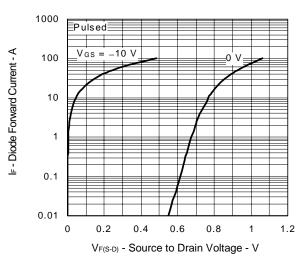


★ SWITCHING CHARACTERISTICS

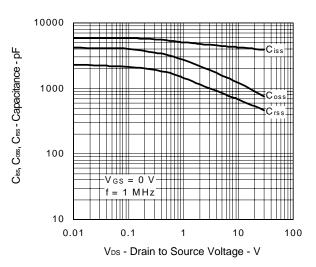


ID - Drain Current - A

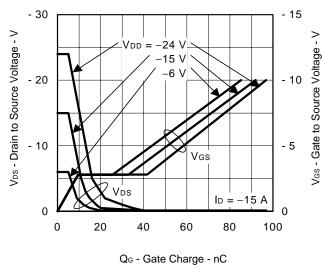
SOURCE TO DRAIN DIODE FORWARD VOLTAGE

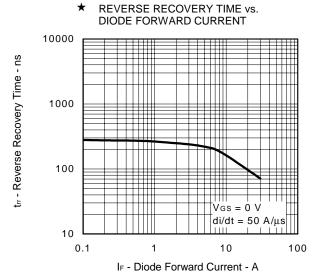


★ CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



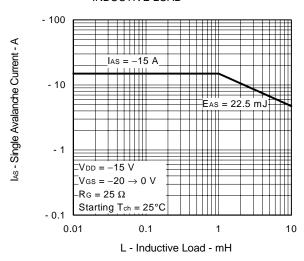
★ DYNAMIC INPUT/OUTPUT CHARACTERISTICS



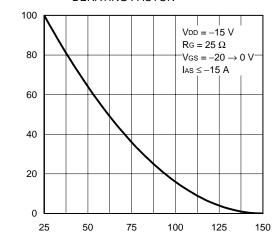


Energy Derating Factor - %

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY DERATING FACTOR



Starting Tch - Starting Channel Temperature - °C



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